

FRED

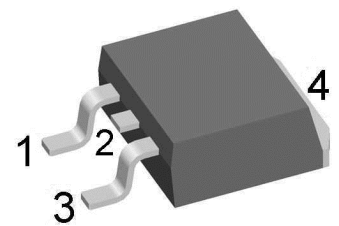
| | | |
|-----------|---|-------|
| V_{RRM} | = | 600 V |
| I_{FAV} | = | 25 A |
| t_{rr} | = | 35 ns |

Fast Recovery Epitaxial Diode Single Diode

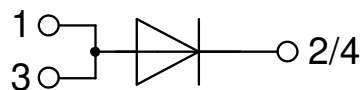
Part number

DSEI25-06AS

Marking on Product: DSEI25-06AS



Backside: cathode



Features / Advantages:

- Planar passivated chips
- Low leakage current
- Very short recovery time
- Improved thermal behaviour
- Very low I_{rm} -values
- Very soft recovery behaviour
- Avalanche voltage rated for reliable operation
- Soft reverse recovery for low EMI/RFI
- Low I_{rm} reduces:
 - Power dissipation within the diode
 - Turn-on loss in the commutating switch

Applications:

- Antiparallel diode for high frequency switching devices
- Antisaturation diode
- Snubber diode
- Free wheeling diode
- Rectifiers in switch mode power supplies (SMPS)
- Uninterruptible power supplies (UPS)

Package: TO-263 (D2Pak)

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

Disclaimer Notice

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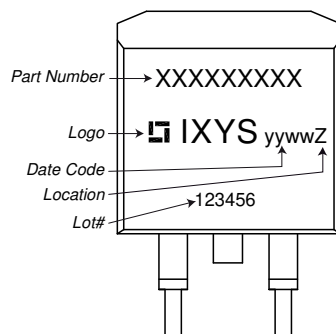
| Fast Diode | | | | Ratings | | | |
|------------|--|---|-------------------------|---------|------|------------|--|
| Symbol | Definition | Conditions | min. | typ. | max. | Unit | |
| V_{RSM} | max. non-repetitive reverse blocking voltage | $T_{VJ} = 25^{\circ}C$ | | | 600 | V | |
| V_{RRM} | max. repetitive reverse blocking voltage | $T_{VJ} = 25^{\circ}C$ | | | 600 | V | |
| I_R | reverse current, drain current | $V_R = 600 V$ | $T_{VJ} = 25^{\circ}C$ | | 100 | μA | |
| | | $V_R = 480 V$ | $T_{VJ} = 125^{\circ}C$ | | 6 | mA | |
| V_F | forward voltage drop | $I_F = 25 A$ | $T_{VJ} = 25^{\circ}C$ | | 1.51 | V | |
| | | $I_F = 50 A$ | | | 1.73 | V | |
| | | $I_F = 25 A$ | $T_{VJ} = 150^{\circ}C$ | | 1.37 | V | |
| | | $I_F = 50 A$ | | | 1.66 | V | |
| I_{FAV} | average forward current | $T_C = 100^{\circ}C$ rectangular $d = 0.5$ | $T_{VJ} = 150^{\circ}C$ | | 25 | A | |
| V_{FO} | threshold voltage | } for power loss calculation only | $T_{VJ} = 150^{\circ}C$ | | 1.10 | V | |
| r_F | slope resistance | | | | 10.6 | m Ω | |
| R_{thJC} | thermal resistance junction to case | | | | 1.2 | K/W | |
| R_{thCH} | thermal resistance case to heatsink | | | 0.50 | | K/W | |
| P_{tot} | total power dissipation | | $T_C = 25^{\circ}C$ | | 105 | W | |
| I_{FSM} | max. forward surge current | $t = 10 ms; (50 Hz), sine; V_R = 0 V$ | $T_{VJ} = 45^{\circ}C$ | | 240 | A | |
| C_J | junction capacitance | $V_R = 400 V \quad f = 1 MHz$ | $T_{VJ} = 25^{\circ}C$ | | 20 | pF | |
| I_{RM} | max. reverse recovery current | } $I_F = 30 A; V_R = 300 V$ $-di_F/dt = 200 A/\mu s$ | $T_{VJ} = 25^{\circ}C$ | | 9 | A | |
| | | | $T_{VJ} = 125^{\circ}C$ | | 14 | A | |
| t_{rr} | reverse recovery time | | $T_{VJ} = 25^{\circ}C$ | | 50 | ns | |
| | | | $T_{VJ} = 125^{\circ}C$ | | 120 | ns | |



| Package TO-263 (D2Pak) | | | Ratings | | | |
|------------------------|------------------------------|----------------------------|---------|------|------|------|
| Symbol | Definition | Conditions | min. | typ. | max. | Unit |
| I_{RMS} | RMS current | per terminal ¹⁾ | | | 35 | A |
| T_{VJ} | virtual junction temperature | | -40 | | 150 | °C |
| T_{op} | operation temperature | | -40 | | 125 | °C |
| T_{stg} | storage temperature | | -40 | | 150 | °C |
| Weight | | | | 1.5 | | g |
| F_C | mounting force with clip | | 20 | | 60 | N |

¹⁾ I_{RMS} is typically limited by the pin-to-chip resistance (1); or by the current capability of the chip (2). In case of (1) and a product with multiple pins for one chip-potential, the current capability can be increased by connecting the pins as one contact.

Product Marking



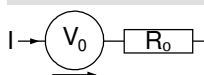
| Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|-------------|-----------------|--------------------|---------------|----------|----------|
| Standard | DSEI25-06AS-TRL | DSEI25-06AS | Tape & Reel | 800 | 520750 |
| Alternative | DSEI25-06AS-TUB | DSEI25-06AS | Tube | 50 | 525170 |

| Similar Part | Package | Voltage class |
|--------------|--------------|---------------|
| DSEI25-06A | TO-220AC (2) | 600 |
| DFE25I600HA | TO-247AD (2) | 600 |

Equivalent Circuits for Simulation

* on die level

$T_{VJ} = 150^{\circ}C$



Fast Diode

| | | | |
|--------------|--------------------|-----|----|
| $V_{0\ max}$ | threshold voltage | 1.1 | V |
| $R_{0\ max}$ | slope resistance * | 7.5 | mΩ |



Outlines TO-263 (D2Pak)



| Dim. | Millimeter | | Inches | |
|------|------------|-------|-------------|-------|
| | min | max | min | max |
| A | 4.06 | 4.83 | 0.160 | 0.190 |
| A1 | typ. 0.10 | | typ. 0.004 | |
| A2 | 2.41 | | 0.095 | |
| b | 0.51 | 0.99 | 0.020 | 0.039 |
| b2 | 1.14 | 1.40 | 0.045 | 0.055 |
| c | 0.40 | 0.74 | 0.016 | 0.029 |
| c2 | 1.14 | 1.40 | 0.045 | 0.055 |
| D | 8.38 | 9.40 | 0.330 | 0.370 |
| D1 | 8.00 | 8.89 | 0.315 | 0.350 |
| D2 | 2.5 | | 0.098 | |
| E | 9.65 | 10.41 | 0.380 | 0.410 |
| E1 | 6.22 | 8.50 | 0.245 | 0.335 |
| e | 2.54 BSC | | 0.100 BSC | |
| e1 | 4.28 | | 0.169 | |
| H | 14.61 | 15.88 | 0.575 | 0.625 |
| L | 1.78 | 2.79 | 0.070 | 0.110 |
| L1 | 1.02 | 1.68 | 0.040 | 0.066 |
| W | typ. 0.02 | 0.040 | typ. 0.0008 | 0.002 |

All dimensions conform with and/or within JEDEC standard.

